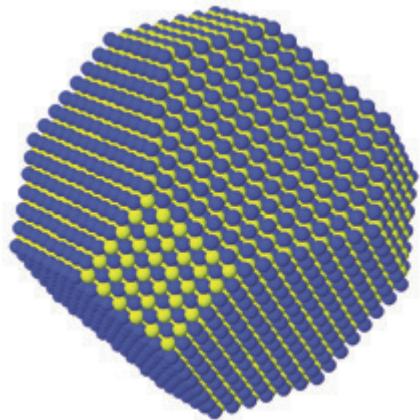


# ON THE NATURE OF STRUCTURAL PHASE TRANSITION IN GeTe



## THE PARENT COMPOUND OF PHASE-CHANGE MATERIALS

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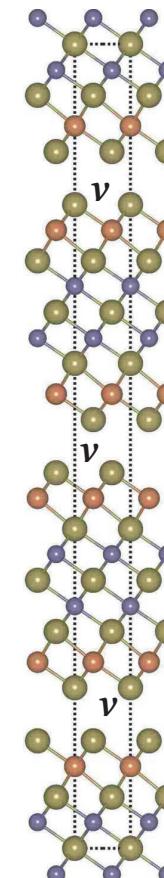
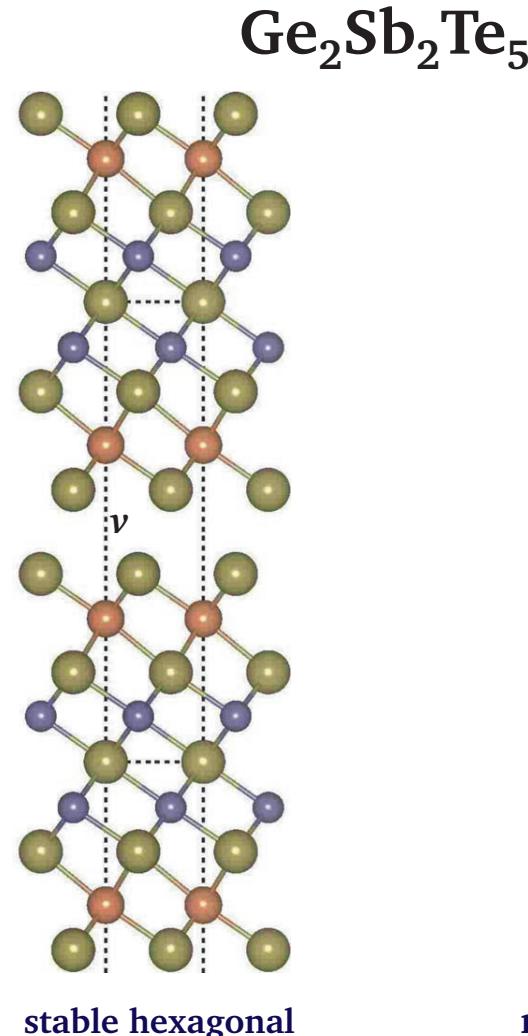
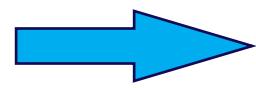
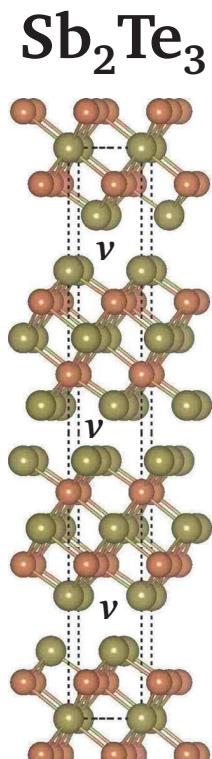
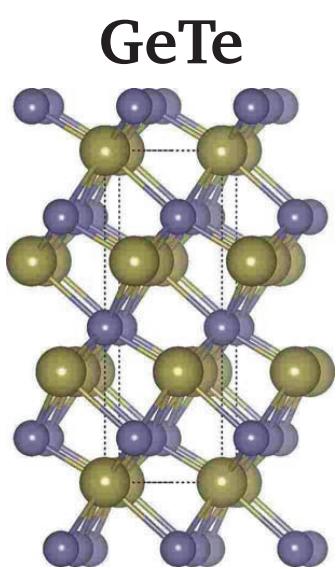
(4) Spallation Neutron Source, Oak Ridge National Laboratory, Oak Ridge, USA

# PHASE-CHANGE MATERIALS

superlattices GST

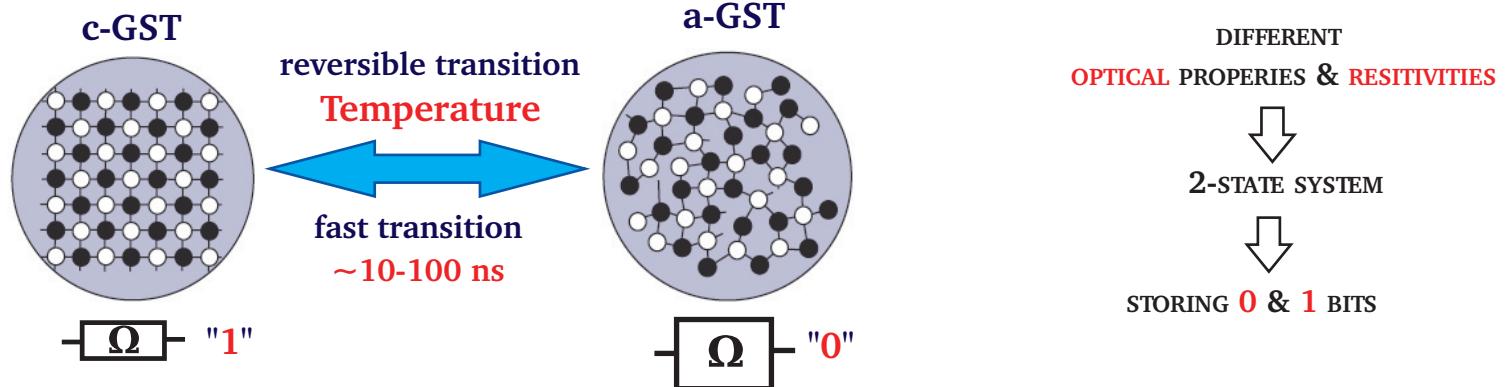


EXPERIMENTS  
HRTEM, XRD, EXAFS



# GST & THEIR APPLICATIONS

## PROPERTIES



## APPLICATIONS



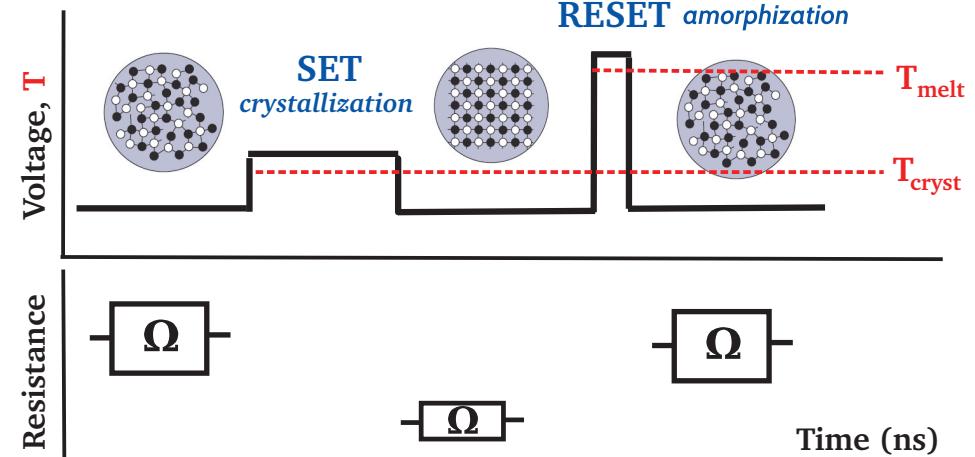
NON-VOLATILE MEMORY DEVICES  
PCM-RAM  
(phase change memory RAM )



OPTICAL STORAGE DEVICES  
rewritable compact disks (CD-RW)  
digital versatile disks (DVDs)  
blu-ray disks (BDs)

REFLECTIVITY CHANGE  
CD/DVD  $\text{Ge}_2\text{Sb}_2\text{Te}_5 = (\text{GeTe})_2 + \text{Sb}_2\text{Te}_3$   
BD  $\text{Ge}_8\text{Sb}_2\text{Te}_{11} = (\text{GeTe})_8 + \text{Sb}_2\text{Te}_3$

RESISTIVITY CHANGE (3-4 orders of magnitude)  
PCMs  $\text{Ge}_2\text{Sb}_2\text{Te}_5 = (\text{GeTe})_2 + \text{Sb}_2\text{Te}_3$

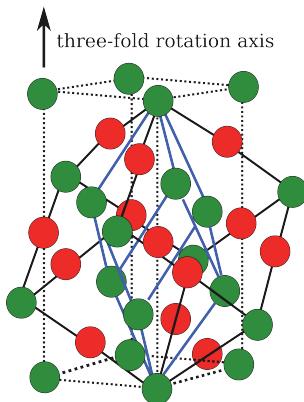


a- to c-phase transition induced by laser beam heating

# GeTe

narrow-gap p-type semiconductor (0.1 - 0.2 eV)  
+  
hole concentration  $p \sim (10^{20} \div 10^{21})/\text{cm}^3$

## RHOMBOHEDRAL R3m



LT ferroelectric  
Peierls distorted



3 short Ge-Te bonds 2.80 Å  
3 long Ge-Te bonds 3.13 Å  
polarization || trigonal axis  
 $\sim 60 \mu\text{C}/\text{cm}^2$

$E_{\text{CAL}} = 0.48 \text{ eV}$

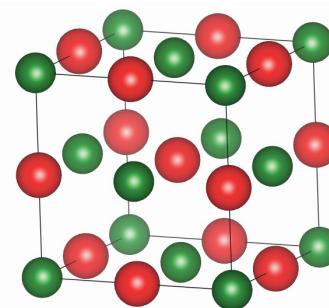
$T_c = 650(100) \text{ K}$



Ge-rich GeTe 733 K  
Te-rich GeTe 633 K



## ROCKSALT Fm-3m



HT paraelectric  
distortions removed



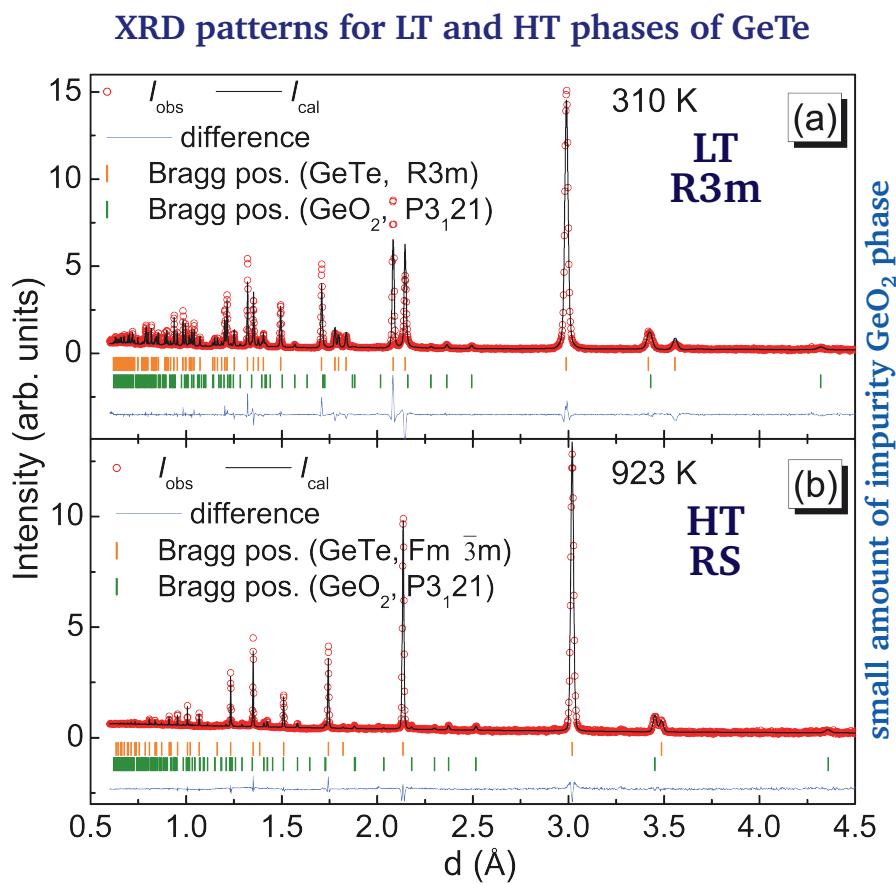
single Ge-Te bond  $\sim 3.0 \text{ \AA}$

$E_{\text{CAL}} = 0.26 \text{ eV}$

# PHASE TRANSITION IN GeTe - EXPERIMENTS

## SAMPLE

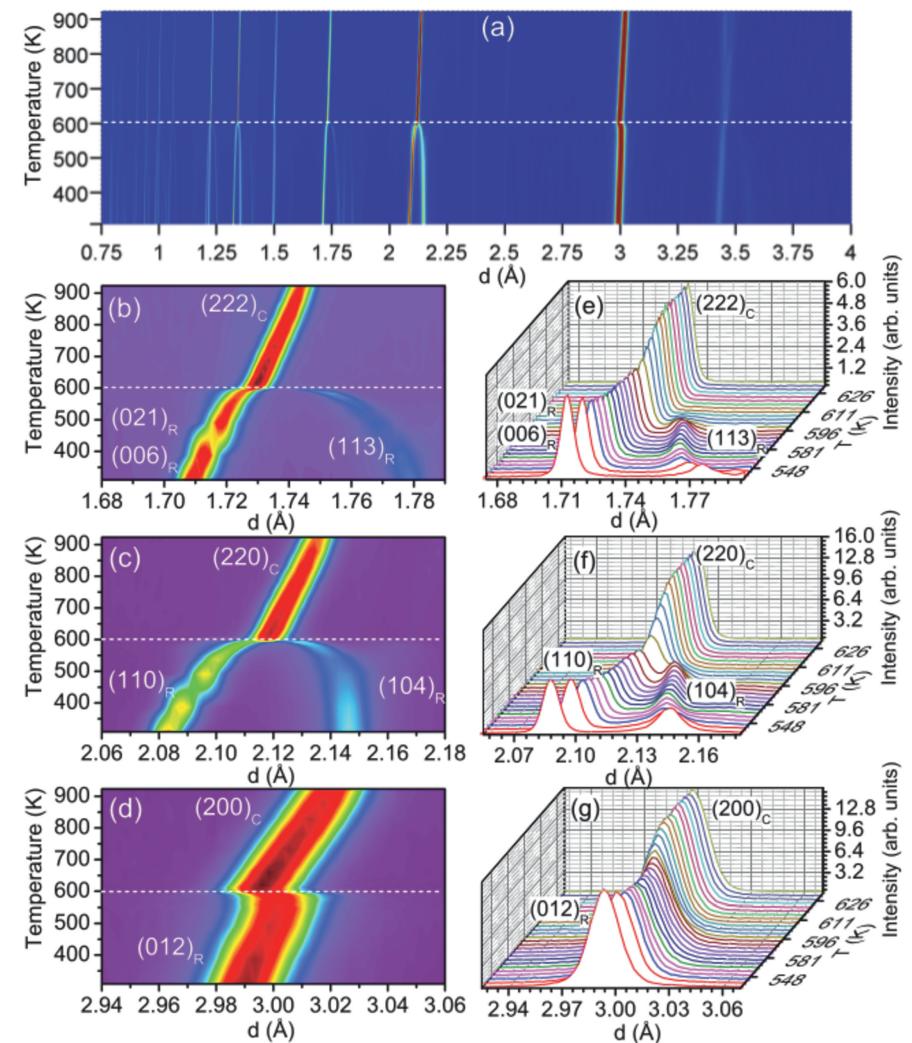
Alfa Aesar powder sample  
claimed to be 99.999% pure  
Mesh = 200



Rietveld profile refinement by FULLPROF  
[J. Rodriguez-Carvajal, <http://www.ill.eu/sites/fullprof>]

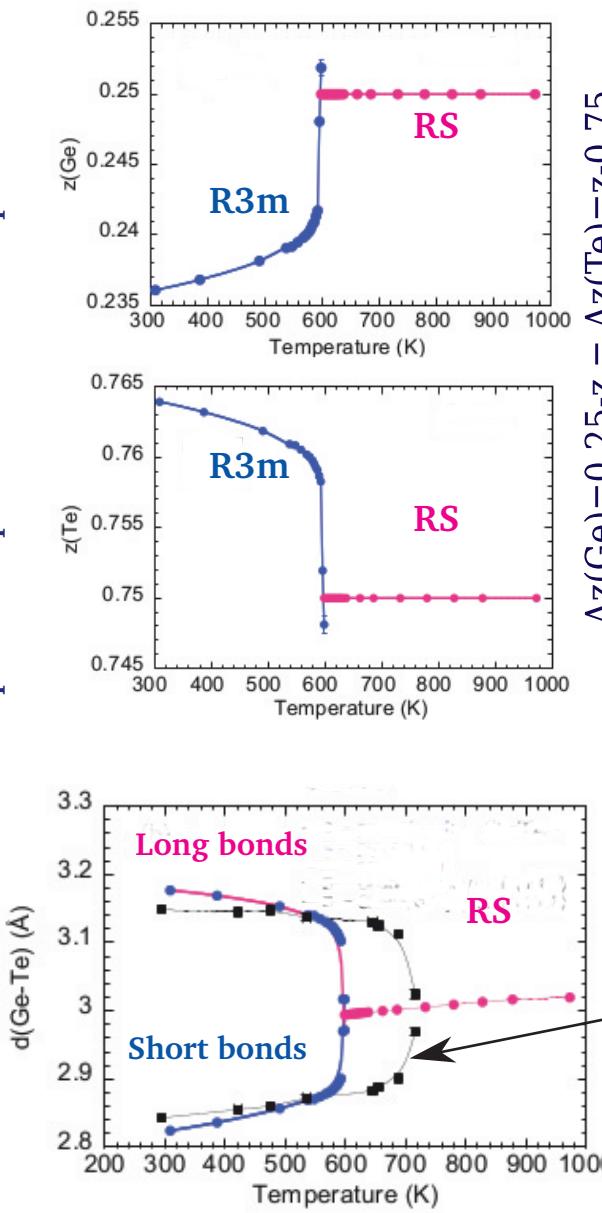
## NEUTRON POWDER DIFFRACTION

TOF powder diffractometer POWGEN  
Spallation Neutron Source @ Oak Ridge National Lab. USA  
neutron central wavelength 1.333  $\text{\AA}$   
 $d$ -spacing 0.42 - 5.4  $\text{\AA}$



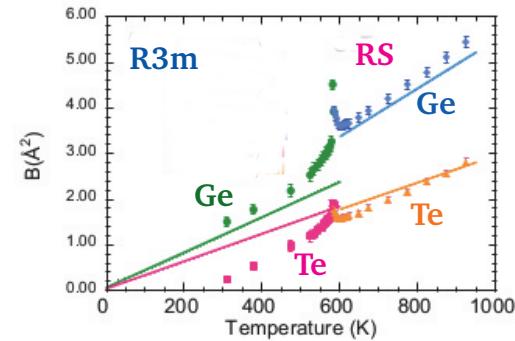
# PHASE TRANSITION IN GeTe - EXPERIMENTS

positional parameters in hex. representation



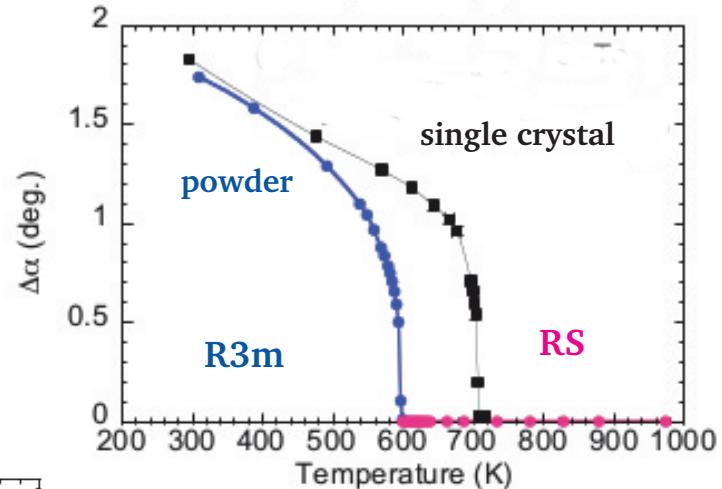
Vanishing distortions  $T > T_c$   
 $T_c = 600 \text{ K}$

$$\Delta z(\text{Ge}) = 0.25 - z = \Delta z(\text{Te}) = z - 0.75$$



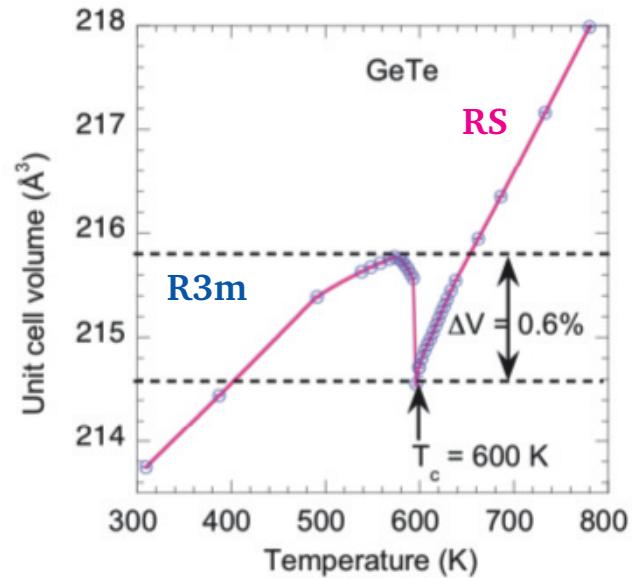
GeTe single crystal  
 Chattopadhyay et al.  
*J. Phys. C* 20, 1431 (1987)

distortion angle  
 $\Delta\alpha = 90^\circ - \alpha$



pseudo-cubic setting

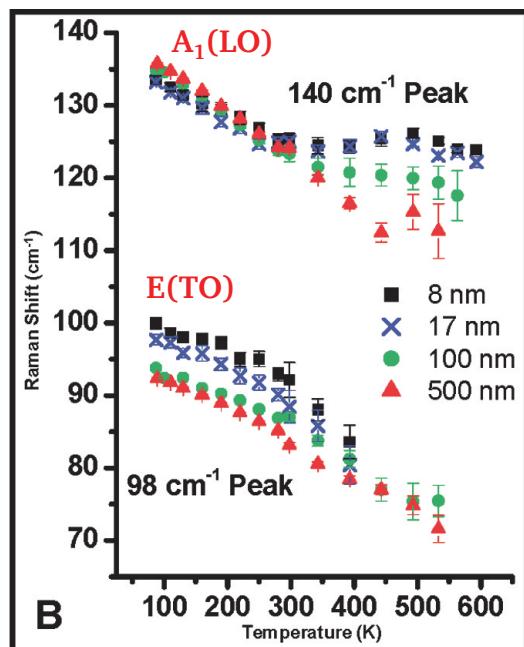
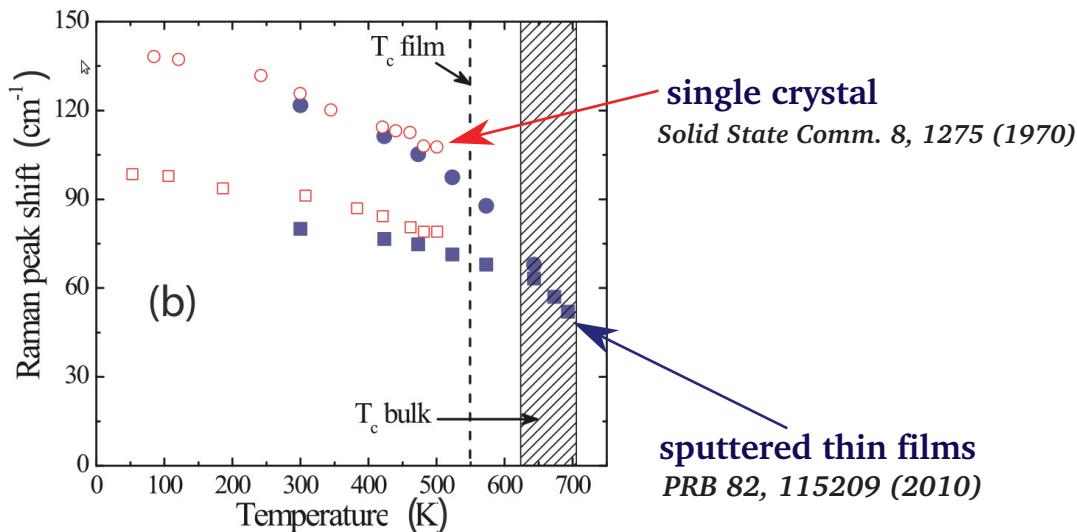
Volume reduction @  $T_c \sim 1\%$



# LONG-STANDING QUESTION: DISPLACIVE OR ORDER-DISORDER ?

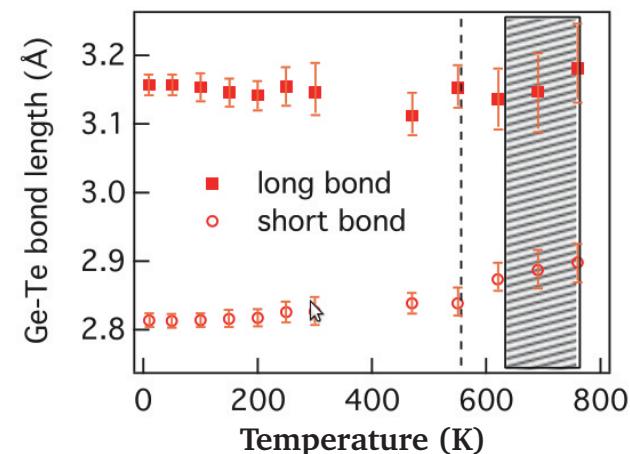
## DISPLACIVE

### RAMAN SCATTERING

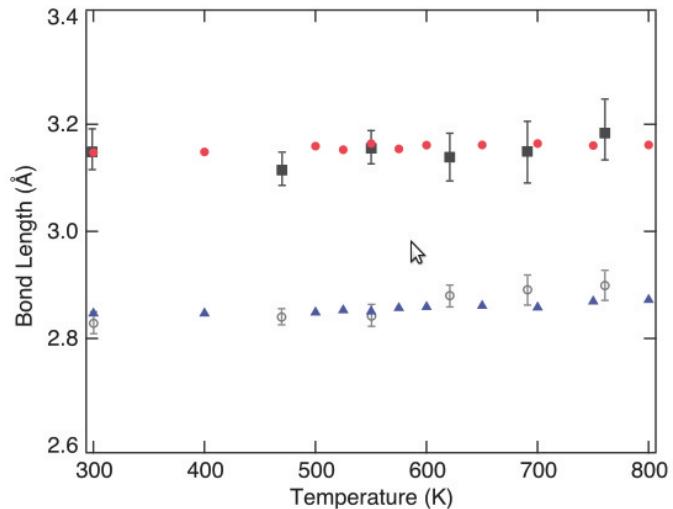


## ORDER-DISORDER

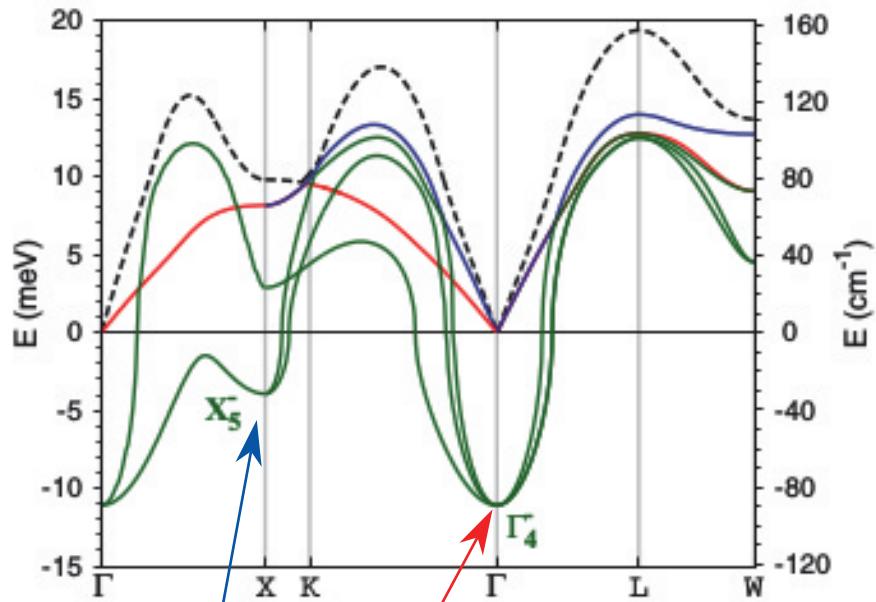
### EXAFS ON FILMS



### PDF ANALYSIS ON FILMS



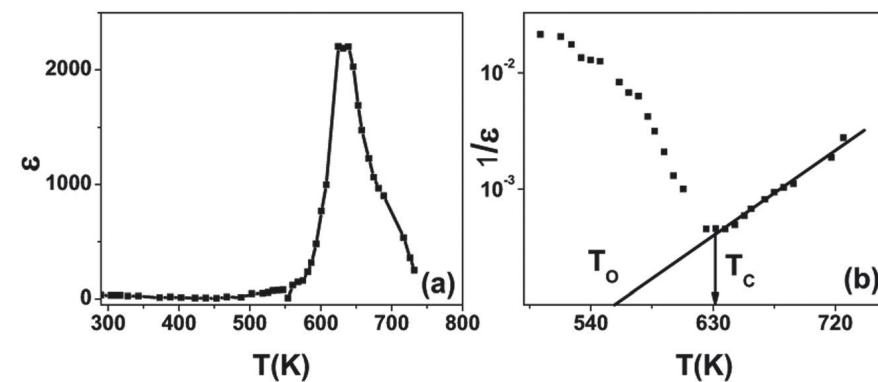
# GeTe - RS



$3.93i$  meV

$11.10i$  meV  
triply degenerate  
 $T_{1u}$  (TO)

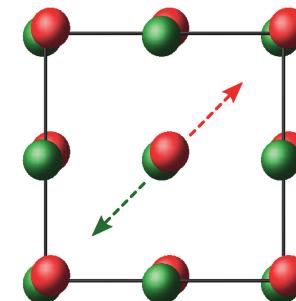
$a_{\text{EXP}} = 6.01-6.02 \text{ \AA}$   
 $a_{\text{CAL}} = 6.011 \text{ \AA}$



Calculated  $\epsilon^{\infty} \sim 100$   
Experimental  $\epsilon^{\infty} \sim 2000$  (just above  $T_c$ )  
Calculated Born  $Z^* \sim 10$   
Calculated  $E_{\text{GAP}} \quad 0.24 \text{ eV}$

GM4- with 3 components condensed

**GROUP THEORY**  
3-dim GM4- Irrep (order parameter consists of 3 components)  
 $Fm\text{-}3m \Rightarrow (\text{GM4-}, e_1 \neq 0, e_2 = e_3 = 0) \Rightarrow I4mm$   
 $Fm\text{-}3m \Rightarrow (\text{GM4-}, e_1 = e_2 \neq 0, e_3 = 0) \Rightarrow Im\bar{m}2$   
 $Fm\text{-}3m \Rightarrow (\text{GM4-}, e_1 = e_2 = e_3 \neq 0) \Rightarrow R3m$

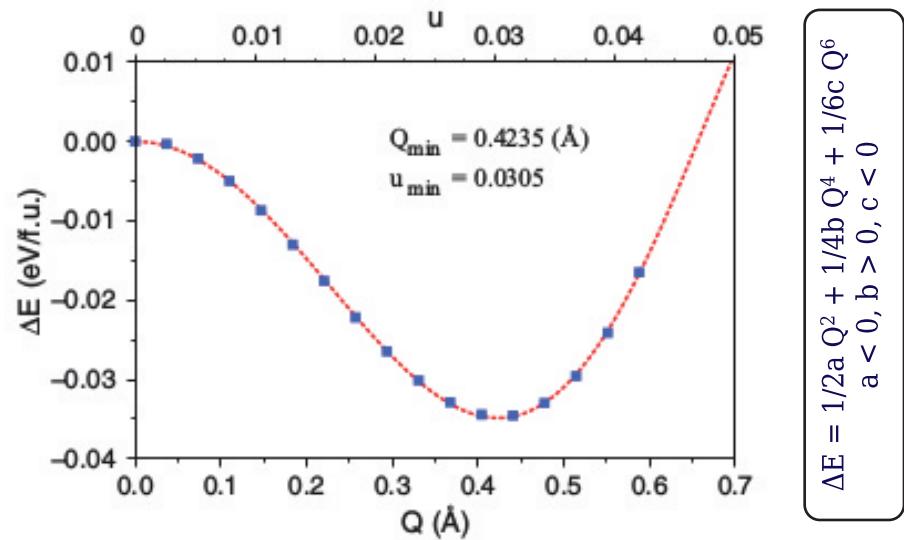


relative displacements  
of Ge and Te sublattices  
along cubic cell  
diagonal ([111] dir)

Condensation of 3 components lowers  $Fm\text{-}3m$  to  $R3m$

# GeTe - R3m

Relative energy vs. amplitude Q of the unstable GM4-

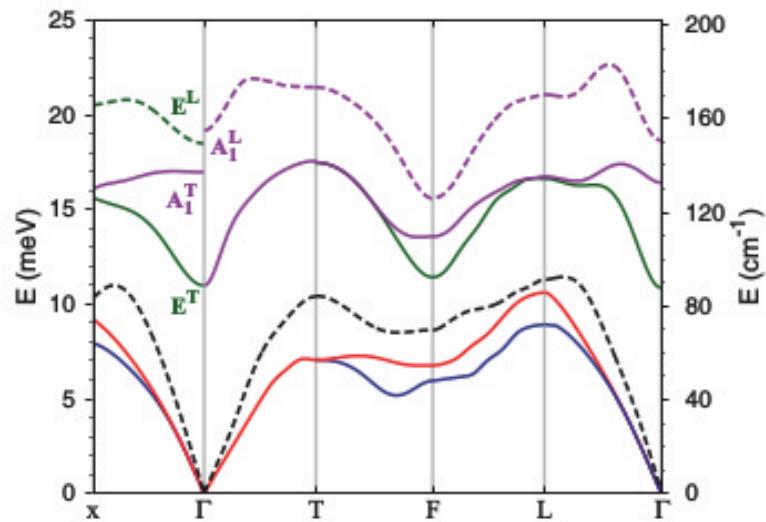


$Q_{\min} = 0.424 \text{ \AA}$ ,  $u_{\min} = 0.03$  ( $0.316 \text{ \AA}$ )  
 $E_{\text{GAP}} = 0.48 \text{ eV}$

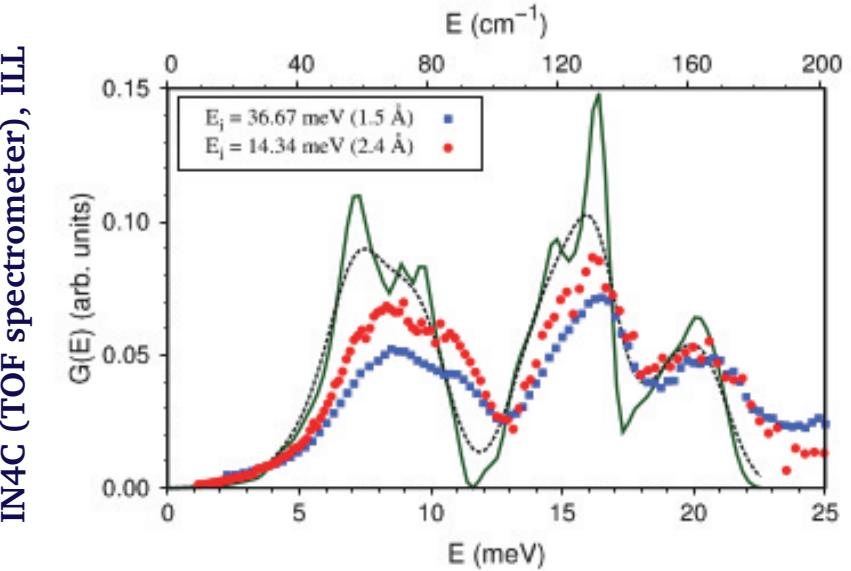
pseudo-cubic		rhombohedral			
cal.	exp.	cal.	exp.		
$a_c$	6.085	5.982	$a_r$	4.373	4.294
$\alpha_c$	88.110	88.247	$\alpha_r$	57.864	58.032
$u$	0.030	0.027	x	0.234	0.236

Exp. (309 K) neutron diffraction (spallation source)

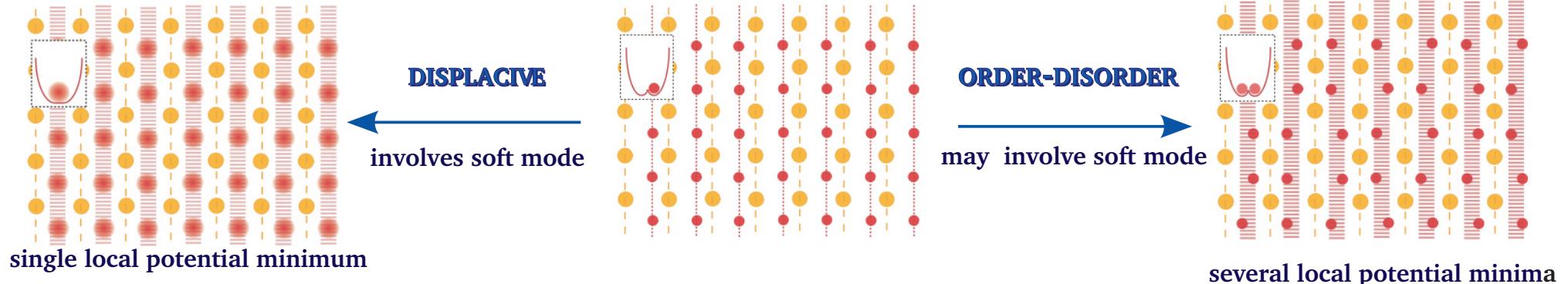
Phonons in R3m - configuration ( $Q_{\min}$ ,  $E_{\min}$ )



	⊥		<>	Exp. (reflectivity)
$\epsilon^\infty$	39.21	34.56	37.66	35-37.5
$Z^*$	5.42	3.30	---	



# PHASE TRANSITION IN GeTe



How to resolve whether the local atomic potential is single or multiwell

local atomic potential barrier described by on-site  $F_{ii}(\mu)$

$$F_{ii}(\mu) > 0$$

SINGLE MINIMUM

$$F_{ii}(\mu) < 0$$

MULTIWELL

Schneider & Stoll  
PRB 13, 1216 (1976)

$F_{ii}(\text{Ge}, \text{Te})$  in GeTe-RS

$$\begin{aligned} F_{xx}(\text{Ge}) &= F_{yy}(\text{Ge}) = F_{zz}(\text{Ge}) = +30.141 \text{ N/m} \\ F_{xx}(\text{Te}) &= F_{yy}(\text{Te}) = F_{zz}(\text{Te}) = +53.974 \text{ N/m} \end{aligned}$$

single minima of local potentials  
for Ge & Te atoms in GeTe-RS

paraelectric-to-ferroelectric phase transition in  $\text{LiNbO}_3$

$$F_{zz}(\text{Li}) < 0, \text{ remaining } F_{ii}(\text{Li}), F_{ii}(\text{Nb}), F_{ii}(\text{O}) > 0$$

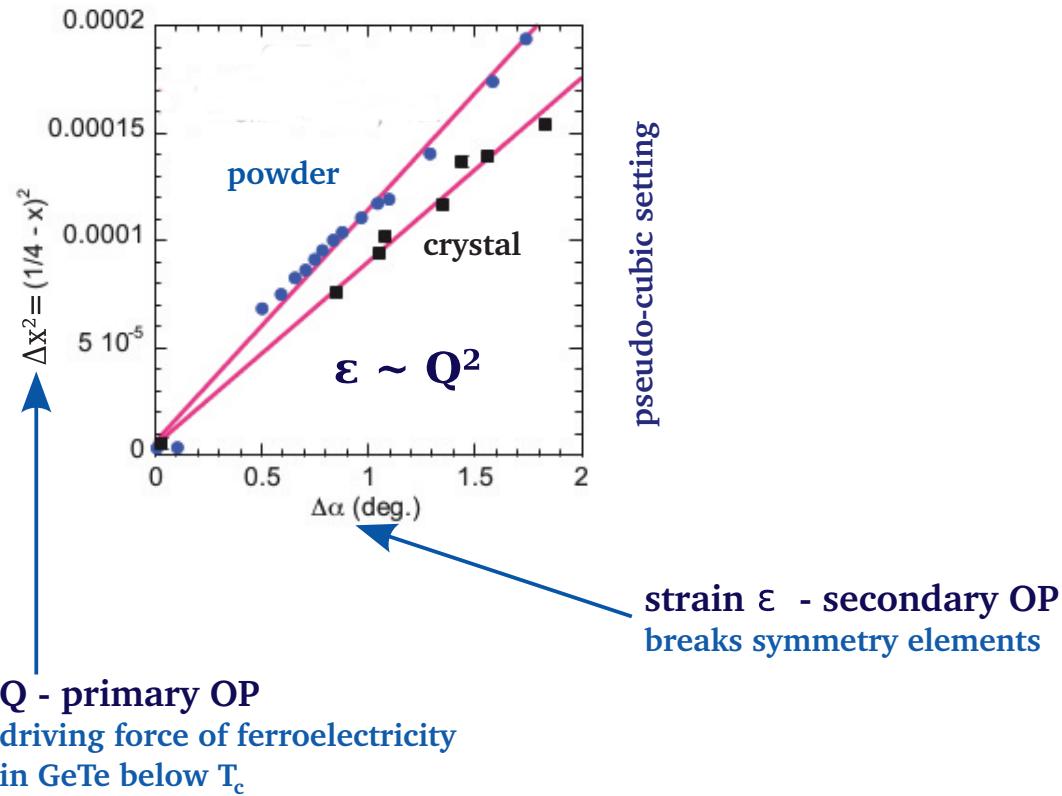
double minimum curve  
for local potential of Li along  $z$

DISPLACIVE PHASE TRANSITION IN GeTe

PRB 61, 272 (2000)

ORDER-DISORDER PHASE TRANSITION IN  $\text{LiNbO}_3$

# 1<sup>ST</sup> OR 2<sup>ND</sup> ORDER PHASE TRANSITION ?



Landau expansion  $F(Q, \epsilon)$



$$\epsilon \sim Q^2$$



2<sup>nd</sup> order phase transition

# CONCLUSIONS

Structural phase transition in GeTe is driven by the condensation of exactly 3 components of the triply degenerate optical transverse soft-phonon mode at the Brillouin zone center.

Phase change in crystalline GeTe is displacive in its origin.

Structural phase transition in GeTe is of 2<sup>nd</sup> order.

Thank you for your attention